

FDP2710 N-Channel PowerTrench[®] MOSFET 250 V, 50 A, 42.5 mΩ

Features

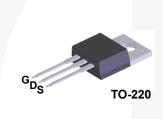
- $R_{DS(on)}$ = 36.3 m Ω (Typ.)@ V_{GS} = 10 V, I_D = 25 A
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench technology for Extremely Low $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$
- High Power and Current Handing Capability
- RoHS Compliant

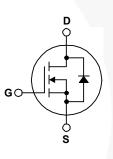
General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Consumer Appliances
- Synchronous Rectification





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter			FDP2710	Unit	
V _{DS}	Drain-Source Voltage		250	V		
V _{GS}	Gate-Source voltage		± 30	V		
ID	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)		50 31.3	AA	
I _{DM}	Drain Current	- Pulsed	(Note 1)	See Figure 9	A	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	145	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3		(Note 3)	4.5	V/ns	
P _D	Power Dissipation (T _C = 25°C) - Derate above 25°C			260 2.1	W W/°C	
T _{J,} T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

Thermal Characteristics

Symbol	Parameter	FDP2710	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	0.48	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

1

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FDP2710 — N-Channel PowerTrench[®] MOSFET

Device Marking Device I		Pacl	nckage Reel Size Tap		e Widt	h	Quantity			
FDP2710 FDP2710 T		TO-	D-220 Tube			N/A		50 units		
Electrica	l Char	racteristics T _c	_C = 25°C unle	ess otherwis	e noted					
Symbol		Parameter		Conditions		Min	Тур	Max	Unit	
Off Characte	ristics									
BV _{DSS} [Drain-Soι	irce Breakdown Volta	ige	$V_{GS} = 0V, I_D = 250\mu A, T_J = 25^{\circ}C$		250			V	
000			re	$I_D = 250 \mu A$, Referenced to $25^{\circ}C$			0.25		V/∘C	
I _{DSS} Z	Zero Gate Voltage Drain Current		nt	$V_{DS} = 250V, V_{GS} = 0V$ $V_{DS} = 250V, V_{GS} = 0V, T_{C} = 125^{\circ}C$				10 500	μΑ μΑ	
I _{GSSF} (Gate-Body Leakage Current, Forward		orward	V _{GS} = 30V, V _{DS} = 0V				100	nA	
I _{GSSR} (Gate-Body Leakage Current, Reverse		Reverse	$V_{GS} = -30V, V_{DS} = 0V$				-100	nA	
On Characte	ristics									
V _{GS(th)} 0	Gate Threshold Voltage			V _{DS} = V _{GS}	_s , I _D = 250μA		3.0	4.0	5.0	V
R _{DS(on)} S	Static Dra	ic Drain-Source On-Resistance		V _{GS} = 10\	/, I _D = 25Α			36.3	42.5	mΩ
9 _{FS} F	Forward Transconductance			V _{DS} = 10V	′, I _D = 25A			63		S
Dynamic Cha	aracteris	tics								•
C _{iss} I	nput Cap	acitance					5470	7280	pF	
C _{oss} (Output Ca	tput Capacitance		V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz			426	570	pF	
	Reverse Transfer Capacitance					-	97	146	pF	
Switching Cl	haracteri	stics							•	
t _{d(on)} 1	Turn-On Delay Time			V _{DD} = 125V, I _D = 50A V _{GS} = 10V, R _{GEN} = 25Ω			80	170	ns	
t _r 1	Turn-On F	urn-On Rise Time					252	515	ns	
t _{d(off)} 1	Turn-Off [Delay Time						112	235	ns
t _f 1	Turn-Off F	all Time				(Note 4)		154	320	ns
Q _g 1	Total Gate	e Charge		$V_{DS} = 125V, I_D = 50A$ $V_{GS} = 10V$ (N				78	101	nC
Q _{gs} (Gate-Sou	rce Charge						34		nC
Q _{gd} (Gate-Drai	n Charge				(Note 4)		18		nC
Drain-Source	e Diode (Characteristics and	Maximum	Ratings						1
I _S Maximum Continuous Drain-Source Dio			ource Diode	e Forward	Current				50	Α
I _{SM} N	Maximum Pulsed Drain-Source Diode F			ward Curr	ent				150	Α
V _{SD} [Drain-Sou	Irce Diode Forward V	oltage	V _{GS} = 0V, I _S = 50A				1.2	V	
t _{rr} F	Reverse F	Recovery Time		V _{GS} = 0V,				163		ns
	Reverse F	Recovery Charge		$dI_F/dt = 10$	0A/μs			1.3		μC

Notes:

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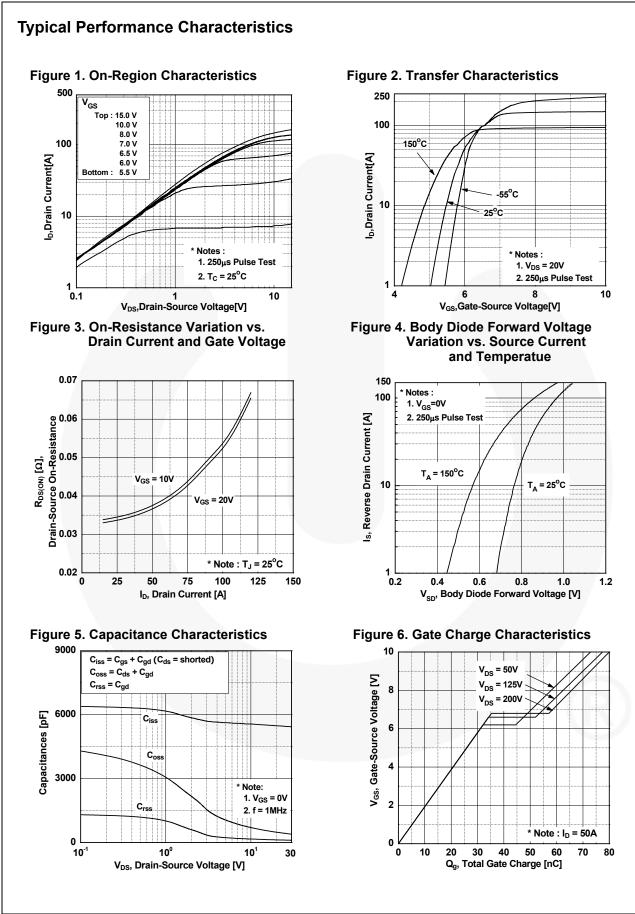
1. Repetitive Rating: Pulse width limited by maximum junction temperature

Package Marking and Ordering Information

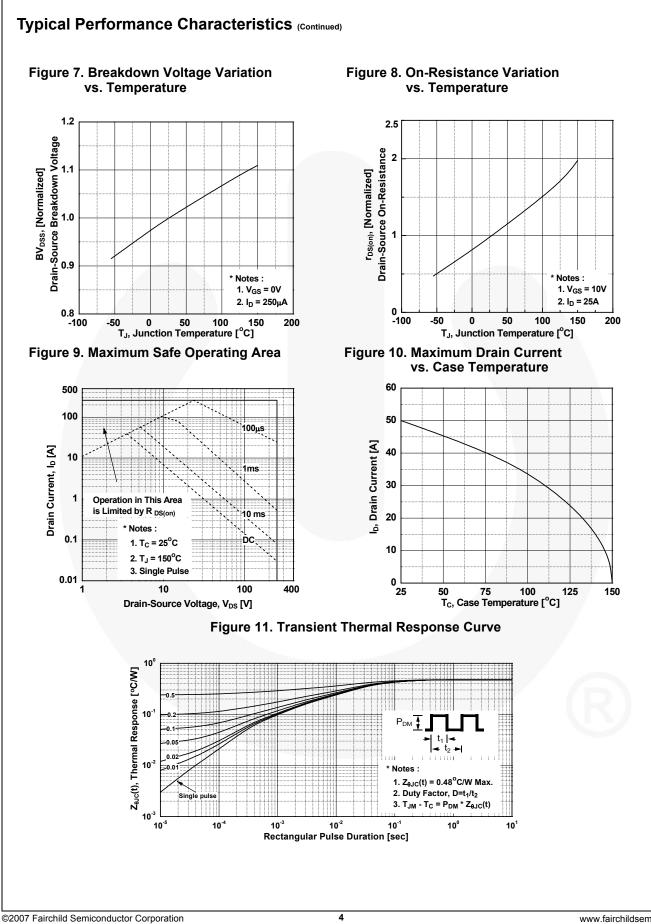
2. L = 1mH, I_{AS} = 17A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C

3. $I_{SD} \leq$ 50A, di/dt \leq 100A/µs, $V_{DD} \leq$ BV_{DSS}, Starting T_J = 25°C

4. Essentially Independent of Operating Temperature Typical Characteristics

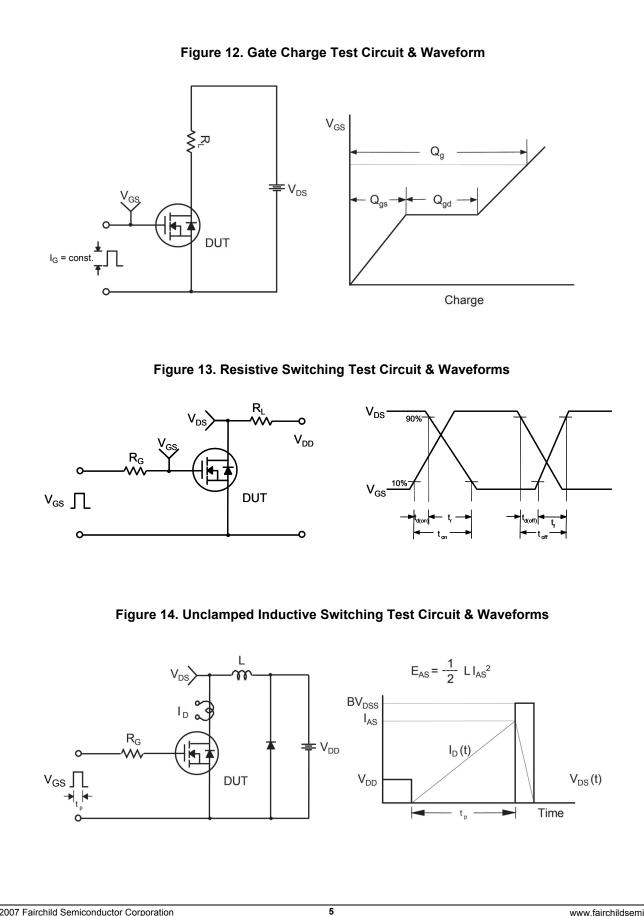


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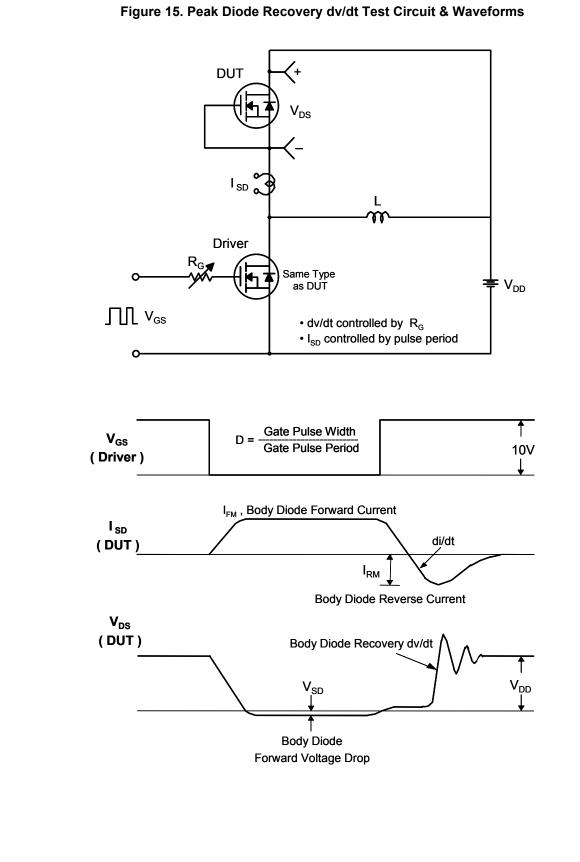


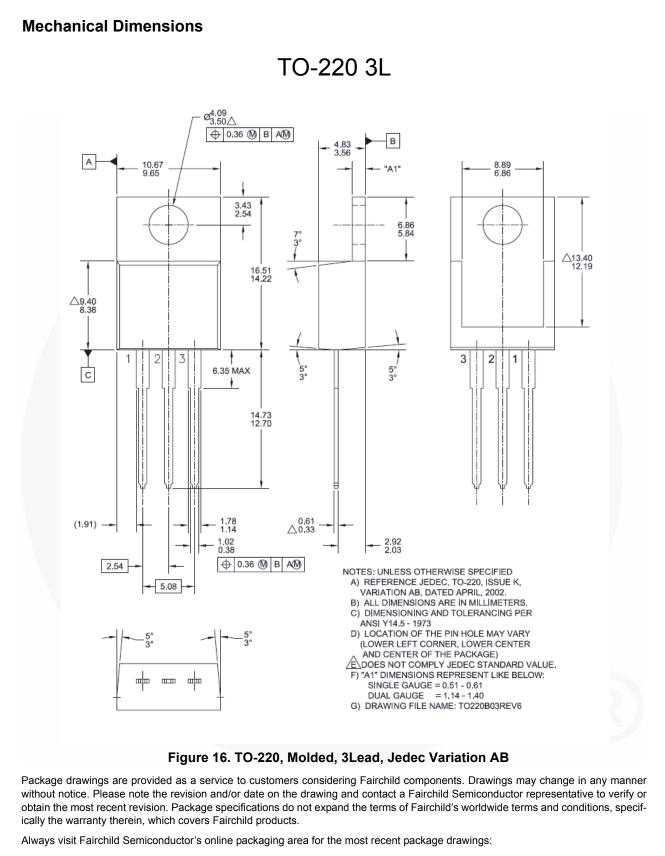
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Dimension in Millimeters

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